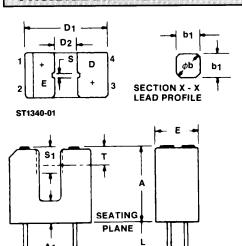


H22A1/2/3

PACKAGE DIMENSIONS

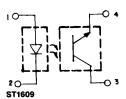


| SYMBOL | MILLIMETERS | | INC | NOTES | | |
|----------------|-------------|------|-----------|-------|---------|--|
| UTWIDOL | MIN. | MAX. | MIN. | MAX. | INO ILO | |
| Α | 10.7 | 11.0 | .422 | .433 | | |
| A, | 3.0 | 3.2 | .119 | .125 | | |
| ₩b | .600 | .750 | .024 | .030 | 2 | |
| b, | .50 NOM. | | .020 NOM. | | 2 | |
| D, | 11.6 | 12.0 | .457 | .472 | | |
| D ₂ | 3.0 | 3.3 | .119 | .129 | | |
| e, | 6.9 | 7.5 | .272 | .295 | | |
| e ₂ | 2.3 | 2.8 | .091 | .110 | | |
| E | 6.15 | 6.35 | .243 | .249 | | |
| L | 8.00 | | .315 | | | |
| S | .85 | 1.0 | .034 | .039 | | |
| S ₁ | 3.45 | 3.75 | .136 | .147 | | |
| Т | 2.6 NOM. | | .103 | 3 | | |

NOTES:

- 1. INCH DIMENSIONS ARE DERIVED FROM MILLIMETERS. 2. FOUR LEADS. LEAD CROSS SECTION IS CONTROLLED BETWEEN 1.27mm (.050") FROM SEATING PLANE AND THE END OF THE LEADS.
- 3. THE SENSING AREA IS DEFINED BY THE "S" DIMENSION AND BY DIMENSION "T" ±0.75mm (±.030 INCH).

PACKAGE OUTLINE



ST1340-02

DESCRIPTION

The H22A Slotted Optical Switch is a gallium arsenide light emitting diode coupled to a silicon photodarlington in a plastic housing. The packaging system is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. The gap in the housing provides a means of interrupting the signal with an opaque material, switching the output from an "ON" to an "OFF" state.

FEATURES

- Opaque housing
- Low cost
- .035" apertures
- High I_{C(ON)}



| Storage Temperature | 55°C to +100°C |
|--|---------------------|
| Operating Temperature | 55°C to +100°C |
| Soldering: Lead Temperature (Iron) Lead Temperature (Flow) | |
| INPUT DIODE | |
| Continuous Forward Current | 60 mA |
| Reverse Voltage | |
| Power Dissipation | 100 mW ^c |
| OUTPUT TRANSISTOR | |
| Collector-Emitter Voltage | 30 Volts |
| Emitter-Collector Voltage | |
| Power Dissipation | 150 mW |

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|-----------------------------|----------------------------|------|-------------|------|-------|---|
| INPUT DIODE | | | | | | |
| Forward Voltage | $V_{\scriptscriptstyle F}$ | | | 1.7 | V | $I_{\scriptscriptstyle F}=60~\text{mA}$ |
| Reverse Breakdown Voltage | V _R | 6.0 | | | ٧ | $I_R = 10\mu A$ |
| Reverse Leakage Current | I _R | _ | | 1.0 | μΑ | V _R = 3 V |
| OUTPUT TRANSISTOR | | | | | | |
| Emitter-Collector Breakdown | BV_{ECO} | 6.0 | | _ | V | $I_E = 100 \ \mu A, Ee = 0$ |
| Collector-Emitter Breakdown | BV _{CEO} | 30 | - | _ | V | I _c = 1 mA, Ee = 0 |
| Collector-Emitter Leakage | I _{CEO} | _ | | 100 | nA | V _{CE} = 25 V, Ee = 0 |
| COUPLED | | | | | | |
| On-State Collector Current | I _{C(ON)} | | See page 3. | | mA | |
| Saturation Voltage | V _{CE(SAT)} | | See page 3. | | V | |
| Turn-On Time | t _{on} | | See page 3. | | μS | |
| Turn-Off Time | t _{off} | | See page 3. | , × | μS | |

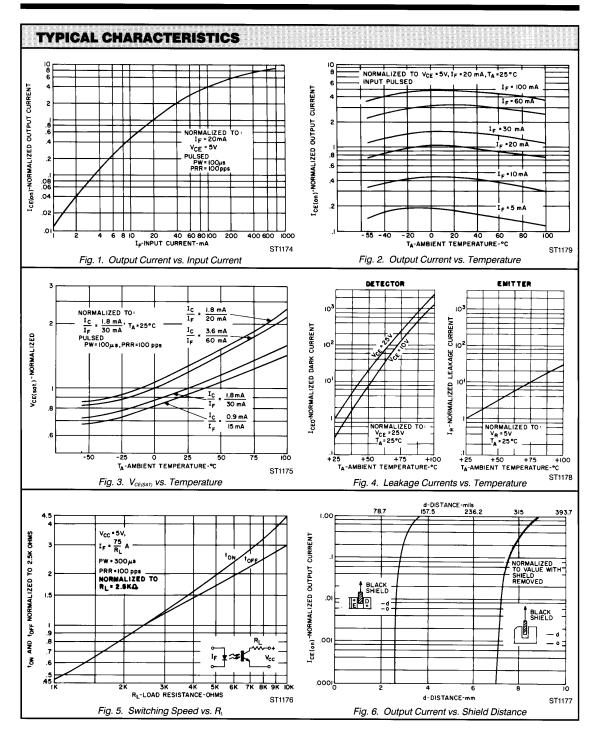
NOTES

- Derate power dissipation linearly 1.33 mW/°C above 25°C.
 Derate power dissipation linearly 2.00 mW/°C above 25°C.
 RMA flux is recommended.
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
 Soldering iron tip 1/16" (1.6 mm) from housing.



| I _{cioni} , V _{ce(sat)} , t _{on} , AND t _{off} | | | | | | |
|--|----------------------|------|------|------|-------|--|
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
| ON-STATE COLLECTOR | CURRENT | | | | | |
| H22A1 | I _{G(ON)} | 0.15 | _ | _ | mA | $I_F = 5mA$, $V_{CE} = 5V$ |
| H22A2 | I _{C(ON)} | 0.30 | _ | _ | mA | $I_F = 5$ mA, $V_{CE} = 5$ V |
| H22A3 | I _{C(ON)} | 0.60 | _ | | mA | $I_F = 5$ mA, $V_{CE} = 5$ V |
| H22A1 | I _{C(ON)} | 1.0 | _ | _ | mA | $I_F = 20$ mA, $V_{CE} = 5$ V |
| H22A2 | I _{C(ON)} | 2.0 | _ | _ | mA | $I_F = 20$ mA, $V_{CE} = 5$ V |
| H22A3 | I _{C(ON)} | 4.0 | | | mA | $I_{\scriptscriptstyle F}=20mA,V_{\scriptscriptstyle CE}=5V$ |
| H22A1 | I _{C(ON)} | 1.9 | | _ | mA | $I_F = 30$ mA, $V_{CE} = 5$ V |
| H22A2 | I _{C(ON)} | 3.0 | _ | | mA | $I_F = 30 \text{mA}, V_{CE} = 5 \text{V}$ |
| H22A3 | I _{C(ON)} | 5.5 | | | mA | $I_F = 30 \text{mA}, V_{CE} = 5 \text{V}$ |
| SATURATION VOLTAGE | | | | | | |
| H22A2 | $V_{CE(SAT)}$ | _ | _ | 0.40 | ٧ | $I_F = 20mA, I_C = 1.8mA$ |
| H22A3 | $V_{\text{CE(SAT)}}$ | | _ | 0.40 | V | $I_F = 20 \text{mA}, I_C = 1.8 \text{mA}$ |
| H22A1 | V _{CE(SAT)} | | | 0.40 | . V | $I_F = 30\text{mA}, I_C = 1.8\text{mA}$ |
| Turn-On Time | t _{on} | | 8 | | μS | $V_{cc} = 5V$, $I_F = 30$ mA, $R_L = 2.5$ Ks |
| Turn-Off Time | t _{off} | | 50 | _ | μS | $V_{cc} = 5V$, $I_F = 30$ mA, $R_I = 2.5$ Ks |







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